

Emiter common (dual digital transistors)

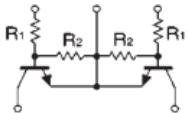
UMG5N / FMG5A

●Features

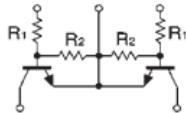
- 1) Two DTC114Y chips in a UMT or SMT package.

●Circuit diagrams

UMG5N



FMG5A



●Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Supply voltage	Vcc	50	V
	VIN	40	V
		-6	
Output current	Io	100	mA
Power dissipation	UMG5N	150 (TOTAL)	mW *1
	FMG5A	300 (TOTAL)	
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55~+150	°C

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

●Package, marking, and packaging specifications

Part No.	UMG5N	FMG5A
Package	UMT5	SMT5
Marking	G5	G5
Code	TR	T148
Basic ordering unit (pieces)	3000	3000

●Electrical characteristics ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	Vi (off)	—	—	0.3	V	Vcc=5V , Io=100 μA
	Vi (on)	1.4	—	—		Vo=0.3V , Io=1mA
Output voltage	Vo (on)	—	0.1	0.3	V	Io=5mA , Ii=0.25mA
Input current	Ii	—	—	0.88	mA	Vi=5V
Output current	Io (off)	—	—	0.5	μA	Vcc=50V , Vi=0V
DC current gain	Gi	68	—	—	—	Io=5mA , Vo=5V
Transition frequency	fr	—	250	—	MHz	Vce=-10V , Ie=5mA, f=100MHz *
Input resistance	R1	7	10	13	kΩ	—
Resistance ratio	R2/R1	3.7	4.7	5.7	—	—